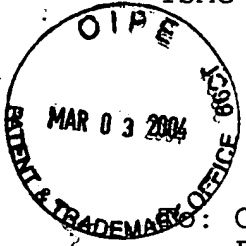


TSMC-03-405



February 27, 2004

To: Commissioner for Patents
P.O.Box 1450
Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572
28 Davis Avenue
Poughkeepsie, N.Y. 12603

Subject: | Serial No. 10/738,416 12/17/03 |

Chia-Chen Liu et al.

METHOD OF FORMING A FLOATING GATE
FOR A SPLIT-GATE FLASH MEMORY DEVICE
| _____ |

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation
In An Application.

The following Patents and/or Publications are submitted to
comply with the duty of disclosure under CFR 1.97-1.99 and
37 CFR 1.56.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being
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P.O. Box 1450, Alexandria, VA 22313-1450, on March , , 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date

SB Ackerman 3/1/04

U.S. Patent 6,570,790 to Harari, "Highly Compact EPROM and Flash EEPROM Devices," describes several EPROM and flash EEPROM devices showing alternative floating gate shapes.

U.S. Patent 6,531,734 to Wu, "Self-aligned Split-gate Flash Memory Cell having an Integrated Source-side Erase Structure and its Contactless Flash Memory Arrays," discloses a split-gate flash memory device and method of manufacture.

U.S. Patent 6,171,906 to Hsieh et al., "Method of Forming Sharp Beak of Poly to Improve Erase Speed in Split Gate Flash," discloses a split-gate flash device and method of manufacture showing a floating gate with an erasing tip formed using LOCOS.

U.S. Patent 6,165,845 to Hsieh et al., "Method to Fabricate Poly Tip in Split-gate Flash," describes a split-gate flash device and method of manufacture.

Sincerely,



Stephen B. Ackerman,
Reg. No. 37761

(Use several sheets if necessary)

Agitation Number

10/738,416

Chia-Chen Liu

12/17/03

Group Art Unit

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[illegible]

FOREIGN PATENT DOCUMENTS

[illegible]

OTHER DOCUMENTS (Including Author, Title, Date, Portion or Pages, Etc.)

[illegible]

ΕΙΣΗΓΗΤΗΣ

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.